

## EAST Search History

| Ref # | Hits | Search Query   | DBs   | Default Operator | Plurals | Time Stamp          |
|-------|------|--|---|------------------|---------|---------------------|
| L1    | 1501 | (438/151).CCLS.  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>IBM_TDB | OR               | OFF     | 2006/10/27 16:17    |
| L2    | 1378 | (438/303).CCLS.  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | OFF     | 2006/10/27<br>16:29 |
| L3    | 6936 | ((257/61,66,344,408,900,E21.435,<br>E29.278) or (438/306,595)).CCLS.                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | OFF     | 2006/10/27 16:31    |
| L4    | 3751 | (L1 L2 L3) and (LDD (lightly adj<br>doped adj drain))                                | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27<br>17:08 |
| L5    | 511  | L4 and (taper\$4)  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27<br>16:43 |
| L6    | 481  | L5 and (@ad<"20040419"<br>@rlad<"20040419")  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27<br>17:09 |
| L7    | 468  | L6 and ((insulat\$3 dielectric) adj<br>(layer film))                                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27<br>16:47 |
| L8    | 153  | L6 and (second adj (insulat\$3<br>dielectric) adj (layer film))                      | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27<br>16:50 |
| L9    | 48   | (L1 L2 L3) and (endpoint near\$5<br>detect\$3)                                       | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27 17:55    |
| L10   | 45   | L9 and (@ad<"20040419"<br>@rlad<"20040419")  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27<br>17:56 |
| L11   | 21   | L10 and (wet near\$3 etch\$3)  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27 17:27    |
| L12   | 2638 | (L1 L2 L3) and (((insulator<br>insulating dielectric) near\$4 gate)<br>same nitride) | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB           | OR               | ON      | 2006/10/27<br>17:56 |

## EAST Search History

|     |      |  |   |    |    |                     |
|-----|------|--|---|----|----|---------------------|
| L13 | 2441 | L12 and (@ad<"20040419"<br>@rlad<"20040419")                                       | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB | OR | ON | 2006/10/27 17:57    |
| L14 | 1815 | (L1 L2 L3) and (((insulator<br>insulating dielectric) near4 gate)<br>with nitride) | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB | OR | ON | 2006/10/27<br>17:56 |
| L15 | 1675 | L14 and (@ad<"20040419"<br>@rlad<"20040419")                                       | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>IBM_TDB | OR | ON | 2006/10/27 17:57    |